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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	481000
Total RAM Bits	33792000
Number of I/O	584
Number of Gates	-
Voltage - Supply	0.97V ~ 1.08V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (Tj)
Package / Case	1152-BBGA, FCBGA
Supplier Device Package	1152-FCBGA (35x35)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/mpf500tls-fcg1152i

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4 Device Offering

The following table lists the PolarFire FPGA device options using the MPF300T as an example. The MPF100T, MPF200T, and MPF500T device densities have identical offerings.

Table 1 • PolarFire FPGA Device Options

Device Options	Extended Commercial 0 °C–100 °C	Industrial –40 °C–100 °C	STD	–1	Transceivers T	Lower Static Power L	Data Security S
MPF300T	Yes	Yes	Yes	Yes	Yes		
MPF300TL	Yes	Yes	Yes		Yes	Yes	
MPF300TS		Yes	Yes	Yes	Yes		Yes
MPF300TLS		Yes	Yes		Yes	Yes	Yes

5 Silicon Status

There are three silicon status levels:

- **Advanced**—initial estimated information based on simulations
- **Preliminary**—information based on simulation and/or initial characterization
- **Production**—final production silicon data

The following table shows the status of the PolarFire FPGA device.

Table 2 • PolarFire FPGA Silicon Status

Device	Silicon Status
MPF100T, TL, TS, TLS	Preliminary
MPF200T, TL, TS, TLS	Preliminary
MPF300T, TL, TS, TLS	Preliminary
MPF500T, TL, TS, TLS	Preliminary

6.2.2.1 Power-Supply Ramp Times

The following table shows the allowable power-up ramp times. Times shown correspond to the ramp of the supply from 0 V to the minimum recommended voltage as specified in the section [Recommended Operating Conditions](#) (see page 6). All supplies must rise and fall monotonically.

Table 10 • Power-Supply Ramp Times

Parameter	Symbol	Min	Max	Unit
FPGA core supply	V _{DD}	0.2	50	ms
Transceiver core supply	V _{DDA}	0.2	50	ms
Must connect to 1.8 V supply	V _{DD18}	0.2	50	ms
Must connect to 2.5 V supply	V _{DD25}	0.2	50	ms
Must connect to 2.5 V supply	V _{DDA25}	0.2	50	ms
HSIO bank I/O power supplies	V _{DDI} [0,1,6,7]	0.2	50	ms
GPIO bank I/O power supplies	V _{DDI} [2,4,5]	0.2	50	ms
Bank 3 dedicated I/O buffers (GPIO)	V _{DDI3}	0.2	50	ms
GPIO bank auxiliary power supplies	V _{DDAUX} [2,4,5]	0.2	50	ms
Transceiver reference clock supply	V _{DD_XCVR_CLK}	0.2	50	ms
Global V _{REF} for transceiver reference clocks	XCVR _{VREF}	0.2	50	ms

Note: For proper operation of programming recovery mode, if a VDD supply brownout occurs during programming, a minimum supply ramp down time for only the VDD supply is recommended to be 10 ms or longer by using a programmable regulator or on-board capacitors.

6.2.2.2 Hot Socketing

The following table lists the hot-socketing DC characteristics over recommended operating conditions.

Table 11 • Hot Socketing DC Characteristics over Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Current per transceiver Rx input pin (P or N single-ended) ^{1, 2}	XCVR _{RX_HS}			±4	mA	V _{DDA} = 0 V
Current per transceiver Tx output pin (P or N single-ended) ³	XCVR _{TX_HS}			±10	mA	V _{DDA} = 0 V
Current per transceiver reference clock input pin (P or N single-ended) ⁴	XCVR _{REF_HS}			±1	mA	V _{DD_XCVR_CLK} = 0 V
Current per GPIO pin (P or N single-ended) ⁵	I _{GPIO_HS}			±1	mA	V _{DDiX} = 0 V
Current per HSIO pin (P or N single-ended)						Hot socketing is not supported in HSIO.

- Assumes that the device is powered-down, all supplies are grounded, AC-coupled interface, and input pin pairs are driven by a CML driver at the maximum amplitude (1 V pk–pk) that is toggling at any rate with PRBS7 data.
- Each P and N transceiver input has less than the specified maximum input current.
- Each P and N transceiver output is connected to a 40 Ω resistor (50 Ω CML termination – 20% tolerance) to the maximum allowed output voltage (V_{DDAmax} + 0.3 V = 1.4 V) through an AC-coupling capacitor with all PolarFire device supplies grounded. This shows the current for a worst-case DC coupled interface. As an AC-coupled interface, the output signal will settle at ground and no hot socket current will be seen.
- V_{DD_XCVR_CLK} is powered down and the device is driven to –0.3 V < V_{IN} < V_{DD_XCVR_CLK}.
- V_{DDiX} is powered down and the device is driven to –0.3 V < V_{IN} < GPIO V_{DDimax}.

I/O Standard	V _{DDI} Min (V)	V _{DDI} Typ (V)	V _{DDI} Max (V)	V _{OL} Min (V)	V _{OL} Max (V)	V _{OH} Min (V)	V _{OH} Max (V)	I _{OL} ^{2,6} mA	I _{OH} ^{2,6} mA
HSTL135I ⁴	1.283	1.35	1.418	0.2	0.8	x	x	V _{OL} /50	(V _{DDI} - V _{OH})/50
HSTL135II ⁴	1.283	1.35	1.418	0.2	0.8	x	x	V _{OL} /25	(V _{DDI} - V _{OH})/25
HSTL12I ⁴	1.14	1.2	1.26	0.1	0.9	x	x	V _{OL} /50	(V _{DDI} - V _{OH})/50
HSTL12II ⁴	1.14	1.2	1.26	0.1	0.9	x	x	V _{OL} /25	(V _{DDI} - V _{OH})/25
HSUL18I ⁴	1.71	1.8	1.89	0.1	0.9	x	x	V _{OL} /55	(V _{DDI} - V _{OH})/55
HSUL18II ⁴	1.71	1.8	1.89	0.1	0.9	x	x	V _{OL} /25	(V _{DDI} - V _{OH})/25
HSUL12I ⁴	1.14	1.2	1.26	0.1	0.9	x	x	V _{OL} /40	(V _{DDI} - V _{OH})/40
POD12I ^{4,5}	1.14	1.2	1.26	0.5	x	x	x	V _{OL} /48	(V _{DDI} - V _{OH})/48
POD12II ^{4,5}	1.14	1.2	1.26	0.5	x	x	x	V _{OL} /34	(V _{DDI} - V _{OH})/34

1. Drive strengths per PCI specification V/I curves.
2. Refer to [UG0686: PolarFire FPGA User I/O User Guide](#) for details on supported drive strengths.
3. For external stub-series resistance. This resistance is on-die for GPIO.
4. I_{OL}/I_{OH} units for impedance standards in amps (not mA).
5. VOH_MAX based on external pull-up termination (pseudo-open drain).
6. The total DC sink/source current of all IOs within a lane is limited as follows:
 - a. HSIO lane: 120 mA per 12 IO buffers.
 - b. GPIO lane: 160 mA per 12 IO buffers.

Note: 3.3 V and 2.5 V are only supported in GPIO banks.

6.3.2 Differential DC Input and Output Levels

The follow tables list the differential DC I/O levels.

Table 14 • Differential DC Input Levels

I/O Standard	Bank Type	VICM_RANGE Libero Setting	V _{ICM} ^{1,3} Min (V)	V _{ICM} ^{1,3} Typ (V)	V _{ICM} ^{1,3} Max (V)	V _{ID} ² Min (V)	V _{ID} Typ (V)	V _{ID} Max (V)
LVDS33	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.35	0.6
		Low	0.05	0.4	0.8	0.1	0.35	0.6
LVDS25	GPIO	Mid (default)	0.6	1.25	2.35	0.1	0.35	0.6
		Low	0.05	0.4	0.8	0.1	0.35	0.6
LVDS18 ⁴	GPIO	Mid (default)	0.6	1.25	1.65	0.1	0.35	0.6

I/O Standard	Bank Type	V _{ocm} ¹ Min (V)	V _{ocm} Typ (V)	V _{ocm} Max (V)	V _{od} ² Min (V)	V _{od} ² Typ (V)	V _{od} ² Max (V)
MLVDSE25 ³	GPIO		1.25		0.396	0.442	0.453
LVPECLE33 ³	GPIO		1.65		0.664	0.722	0.755
MIPIE25 ³	GPIO		0.25		0.1	0.22	0.3

1. V_{ocm} is the output common mode voltage.
2. V_{od} is the output differential voltage.
3. Emulated output only.

6.3.3 Complementary Differential DC Input and Output Levels

The following tables list the complementary differential DC I/O levels.

Table 16 • Complementary Differential DC Input Levels

I/O Standard	V _{DDI} Min (V)	V _{DDI} Typ (V)	V _{DDI} Max (V)	V _{ICM} ^{1,3} Min (V)	V _{ICM} ^{1,3} Typ (V)	V _{ICM} ^{1,3} Max (V)	V _{ID} ² Min (V)	V _{ID} Max (V)
SSTL25I	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL25II	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
SSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
HSUL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
POD12I	1.14	1.2	1.26	0.787	0.840	0.895	0.1	
POD12II	1.14	1.2	1.26	0.787	0.840	0.895	0.1	

1. V_{ICM} is the input common mode voltage.
2. V_{ID} is the input differential voltage.
3. V_{ICM} rules are as follows:
 - a. V_{ICM} must be less than V_{DDI} - 0.4V;
 - b. V_{ICM} + V_{ID}/2 must be < V_{DDI} + 0.4 V;
 - c. V_{ICM} - V_{ID}/2 must be > V_{SS} - 0.3 V.

Min (%)	Typ	Max (%)	Unit	Condition
-20	60	20	Ω	$V_{DDI} = 1.2\text{ V}$
-20	120	20	Ω	$V_{DDI} = 1.2\text{ V}$

Note: Thevenin impedance is calculated based on independent P and N as measured at 50% of V_{DDI} . For 50 Ω /75 Ω /150 Ω cases, nearest supported values of 40 Ω /60 Ω /120 Ω are used.

Table 19 • Single-Ended Termination to VDDI (Internal Parallel Termination to VDDI)

Min (%)	Typ	Max (%)	Unit	Condition
-20	34	20	Ω	$V_{DDI} = 1.2\text{ V}$
-20	40	20	Ω	$V_{DDI} = 1.2\text{ V}$
-20	48	20	Ω	$V_{DDI} = 1.2\text{ V}$
-20	60	20	Ω	$V_{DDI} = 1.2\text{ V}$
-20	80	20	Ω	$V_{DDI} = 1.2\text{ V}$
-20	120	20	Ω	$V_{DDI} = 1.2\text{ V}$
-20	240	20	Ω	$V_{DDI} = 1.2\text{ V}$

Note: Measured at 80% of V_{DDI} .

Table 20 • Single-Ended Termination to VSS (Internal Parallel Termination to VSS)

Min (%)	Typ	Max (%)	Unit	Condition
-20	120	20	Ω	$V_{DDI} = 1.8\text{ V}/1.5\text{ V}$
-20	240	20	Ω	$V_{DDI} = 1.8\text{ V}/1.5\text{ V}$
-20	120	20	Ω	$V_{DDI} = 1.2\text{ V}$
-20	240	20	Ω	$V_{DDI} = 1.2\text{ V}$

Note: Measured at 50% of V_{DDI} .

6.3.5 GPIO On-Die Termination

The following table lists the on-die termination calibration accuracy specifications for GPIO bank.

Table 21 • On-Die Termination Calibration Accuracy Specifications for GPIO Bank

Parameter	Description	Min (%)	Typ	Max (%)	Unit	Condition
Differential termination ¹	Internal differential termination	-20	100	20	Ω	$V_{ICM} < 0.8\text{ V}$
		-20	100	40	Ω	$0.6\text{ V} < V_{ICM} < 1.65\text{ V}$
		-20	100	80	Ω	$1.4\text{ V} < V_{ICM}$
Single-ended thevenin termination ^{2,3}	Internal parallel thevenin termination	-40	50	20	Ω	$V_{DDI} = 1.8\text{ V}/1.5\text{ V}$
		-40	75	20	Ω	$V_{DDI} = 1.8\text{ V}$
		-40	150	20	Ω	$V_{DDI} = 1.8\text{ V}$
		-20	20	20	Ω	$V_{DDI} = 1.5\text{ V}$
		-20	30	20	Ω	$V_{DDI} = 1.5\text{ V}$
		-20	40	20	Ω	$V_{DDI} = 1.5\text{ V}$
		-20	60	20	Ω	$V_{DDI} = 1.5\text{ V}$
		-20	120	20	Ω	$V_{DDI} = 1.5\text{ V}$

Parameter	Description	Min (%)	Typ	Max (%)	Unit	Condition
Single-ended termination to $V_{SS}^{4,5}$	Internal	-20	120	20	Ω	$V_{DDI} = 2.5\text{ V}/1.8\text{ V}/1.5\text{ V}/1.2\text{ V}$
	parallel termination to V_{SS}	-20	240	20	Ω	$V_{DDI} = 2.5\text{ V}/1.8\text{ V}/1.5\text{ V}/1.2\text{ V}$

1. Measured across P to N with 400 mV bias.
2. Thevenin impedance is calculated based on independent P and N as measured at 50% of V_{DDI} .
3. For 50 Ω /75 Ω /150 Ω cases, nearest supported values of 40 Ω /60 Ω /120 Ω are used.
4. Measured at 50% of V_{DDI} .
5. Supported terminations vary with the IO type regardless of V_{DDI} nominal voltage. Refer to Libero for available combinations.

Standard	Description	V_L^1	V_H^1	V_{ID}^2	V_{ICM}^2	$V_{MEAS}^{3,4}$	$V_{REF}^{1,5}$	Unit
HSTL135II	Differential HSTL 1.35 V Class II	V_{ICM}^- .125	V_{ICM}^+ .125	0.250	0.675	0		V
HSTL12	Differential HSTL 1.2 V	V_{ICM}^- .125	V_{ICM}^+ .125	0.250	0.600	0		V
HSUL18I	Differential HSUL 1.8 V Class I	V_{ICM}^- .125	V_{ICM}^+ .125	0.250	0.900	0		V
HSUL18II	Differential HSUL 1.8 V Class II	V_{ICM}^- .125	V_{ICM}^+ .125	0.250	0.900	0		V
HSUL12	Differential HSUL 1.2 V	V_{ICM}^- .125	V_{ICM}^+ .125	0.250	0.600	0		V
POD12I	Differential POD 1.2 V Class I	V_{ICM}^- .125	V_{ICM}^+ .125	0.250	0.600	0		V
POD12II	Differential POD 1.2 V Class II	V_{ICM}^- .125	V_{ICM}^+ .125	0.250	0.600	0		V
MIPI25	Mobile Industry Processor Interface	V_{ICM}^- .125	V_{ICM}^+ .125	0.250	0.200	0		V

1. Measurements are made at typical, minimum, and maximum V_{REF} values. Reported delays reflect worst-case of these measurements. V_{REF} values listed are typical. Input waveform switches between V_L and V_H . All rise and fall times must be 1 V/ns.
2. Differential receiver standards all use 250 mV V_{ID} for timing. V_{ICM} is different between different standards.
3. Input voltage level from which measurement starts.
4. The value given is the differential input voltage.
5. This is an input voltage reference that bears no relation to the V_{REF}/V_{MEAS} parameters found in IBIS models or shown in [Output Delay Measurement—Single-Ended Test Setup](#) (see page 27).
6. Emulated bi-directional interface.

7.1.2 Output Delay Measurement Methodology

The following section provides information about the methodology for output delay measurement.

Table 23 • Output Delay Measurement Methodology

Standard	Description	R_{REF} (Ω)	C_{REF} (pF)	V_{MEAS} (V)	V_{REF} (V)
PCI	PCIe 3.3 V	25	10	1.65	
LVTTTL33	LVTTTL 3.3 V	1M	0	1.65	
LVC MOS33	LVC MOS 3.3 V	1M	0	1.65	
LVC MOS25	LVC MOS 2.5 V	1M	0	1.25	
LVC MOS18	LVC MOS 1.8 V	1M	0	0.90	
LVC MOS15	LVC MOS 1.5 V	1M	0	0.75	
LVC MOS12	LVC MOS 1.2 V	1M	0	0.60	
SSTL25I	Stub-series terminated logic 2.5 V Class I	50	0	V_{REF}	1.25
SSTL25II	SSTL 2.5 V Class II	50	0	V_{REF}	1.25

Parameter	Interface Name	Topology	STD Min	STD Typ	STD Max	-1 Min	-1 Typ	-1 Max	Unit	Clock-to-Data Condition
F _{MAX} 4:1	RX_DDRX_B_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
F _{MAX} 8:1	RX_DDRX_B_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
F _{MAX} 2:1	RX_DDRX_B_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered
F _{MAX} 4:1	RX_DDRX_B_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered
F _{MAX} 8:1	RX_DDRX_B_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered
F _{MAX} 2:1	RX_DDRX_BL_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
F _{MAX} 4:1	RX_DDRX_BL_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
F _{MAX} 8:1	RX_DDRX_BL_A	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, aligned
F _{MAX} 2:1	RX_DDRX_BL_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered
F _{MAX} 4:1	RX_DDRX_BL_C	Rx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered

Parameter	Interface Name	Topology	STD Min	STD Typ	STD Max	-1 Min	-1 Typ	-1 Max	Unit	Forwarded Clock-to-Data Skew
Output F _{MAX} 2:1	TX_DDRX_B_C	Tx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered with PLL
Output F _{MAX} 4:1	TX_DDRX_B_C	Tx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered with PLL
Output F _{MAX} 8:1	TX_DDRX_B_C	Tx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered with PLL
In delay, out delay, DLL delay step sizes			12.7	30	35	12.7	25	29.5	ps	

Table 34 • I/O CDR Switching Characteristics

Parameter	Min	Max	Unit
Data rate	266	1250	Mbps
Receiver Sinusoidal jitter tolerance ¹	0.2		UI

1. Jitter values based on bit error ratio (BER) of 10–12, 80 MHz sinusoidal jitter injected to Rx data.

Note: See the LVDS output buffer specifications for transmit characteristics.

7.2 Clocking Specifications

This section describes the PLL and DLL clocking and oscillator specifications.

7.2.1 Clocking

The following table provides clocking specifications.

Table 35 • Global and Regional Clock Characteristics (–40 °C to 100 °C)

Parameter	Symbol	V _{DD} = 1.0 V STD	V _{DD} = 1.0 V –1	V _{DD} = 1.05 V STD	V _{DD} = 1.05 V –1	Unit	Condition
Global clock F _{MAX}	F _{MAXG}	500	500	500	500	MHz	
Regional clock F _{MAX}	F _{MAXR}	375	375	375	375	MHz	Transceiver interfaces only
	F _{MAXR}	250	250	250	250	MHz	All other interfaces
Global clock duty cycle distortion	T _{D CDG}	190	190	190	190	ps	At 500 MHz

Parameter	Symbol	V _{DD} = 1.0 V STD	V _{DD} = 1.0 V -1	V _{DD} = 1.05 V STD	V _{DD} = 1.05 V -1	Unit	Condition
Regional clock duty cycle distortion	T _{DCDR}	120	120	120	120	ps	At 250 MHz

The following table provides clocking specifications from -40 °C to 100 °C.

Table 36 • High-Speed I/O Clock Characteristics (-40 °C to 100 °C)

Parameter	Symbol	V _{DD} = 1.0 V STD	V _{DD} = 1.0 V -1	V _{DD} = 1.05 V STD	V _{DD} = 1.05 V -1	Unit	Condition
High-speed I/O clock F _{MAX}	F _{MAXB}	1000	1250	1000	1250	MHz	HSIO and GPIO
High-speed I/O clock skew ¹	F _{SKEWB}	30	20	30	20	ps	HSIO without bridging
	F _{SKEWB}	600	500	600	500	ps	HSIO with bridging
	F _{SKEWB}	45	35	45	35	ps	GPIO without bridging
	F _{SKEWB}	75	60	75	60	ps	GPIO with bridging
High-speed I/O clock duty cycle distortion ²	T _{DCB}	90	90	90	90	ps	HSIO without bridging
	T _{DCB}	115	115	115	115	ps	HSIO with bridging
	T _{DCB}	90	90	90	90	ps	GPIO without bridging
	T _{DCB}	115	115	115	115	ps	GPIO with bridging

1. F_{SKEWB} is the worst-case clock-tree skew observable between sequential I/O elements. Clock-tree skew is significantly smaller at I/O registers close to each other and fed by the same or adjacent clock-tree branches. Use the Microsemi Timing Analyzer tool to evaluate clock skew specific to the design.
2. Parameters listed in this table correspond to the worst-case duty cycle distortion observable at the I/O flip flops. IBIS should be used to calculate any additional duty cycle distortion that might be caused by asymmetrical rise/fall times for any I/O standard.

7.2.2

PLL

The following table provides information about PLL.

Table 37 • PLL Electrical Characteristics

Parameter	Symbol	Min	Typ	Max	Unit
Input clock frequency (integer mode)	F _{INI}	1		1250	MHz
Input clock frequency (fractional mode)	F _{INF}	10		1250	MHz
Minimum reference or feedback pulse width ¹	F _{INPULSE}	200			ps
Frequency at the Frequency Phase Detector (PFD) (integer mode)	F _{PHDETI}	1		312	MHz
Frequency at the PFD (fractional mode)	F _{PHDETF}	10	50	125	MHz
Allowable input duty cycle	F _{INDUTY}	25		75	%

Parameter	Modes ¹	STD	STD	-1	-1	Unit
		Min	Max	Min	Max	
Transceiver RX_CLK range (non-deterministic PCS mode with global or regional fabric clocks)	10-bit, max data rate = 1.6 Gbps		160		160	MHz
	16-bit, max data rate = 4.8 Gbps		300		300	MHz
	20-bit, max data rate = 6.0 Gbps		300		300	MHz
	32-bit, max data rate = 10.3125 Gbps		325		325	MHz
	40-bit, max data rate = 10.3125 Gbps (-STD) / 12.7 Gbps (-1) ¹		260		320	MHz
	64-bit, max data rate = 10.3125 Gbps (-STD) / 12.7 Gbps (-1) ¹		165		200	MHz
	80-bit, max data rate = 10.3125 Gbps (-STD) / 12.7 Gbps (-1) ¹		130		160	MHz
	Fabric pipe mode 32-bit, max data rate = 6.0 Gbps		150		150	MHz
Transceiver TX_CLK range (deterministic PCS mode with regional fabric clocks)	8-bit, max data rate = 1.6 Gbps		200		200	MHz
	10-bit, max data rate = 1.6 Gbps		160		160	MHz
	16-bit, max data rate = 3.6 Gbps (-STD) / 4.25 Gbps (-1)		225		266	MHz
	20-bit, max data rate = 4.5 Gbps (-STD) / 5.32 Gbps (-1)		225		266	MHz
	32-bit, max data rate = 7.2 Gbps (-STD) / 8.5 Gbps (-1)		225		266	MHz
	40-bit, max data rate = 9.0 Gbps (-STD) / 10.6 Gbps (-1) ¹		225		266	MHz
	64-bit, max data rate = 10.3125 Gbps (-STD) / 12.7 Gbps (-1) ¹		165		200	MHz
	80-bit, max data rate = 10.3125 Gbps (-STD) / 12.7 Gbps (-1) ¹		130		160	MHz
Transceiver RX_CLK range (deterministic PCS mode with regional fabric clocks)	8-bit, max data rate = 1.6 Gbps		200		200	MHz
	10-bit, max data rate = 1.6 Gbps		160		160	MHz
	16-bit, max data rate = 3.6 Gbps (-STD) / 4.25 Gbps (-1)		225		266	MHz
	20-bit, max data rate = 4.5 Gbps (-STD) / 5.32 Gbps (-1)		225		266	MHz
	32-bit, max data rate = 7.2 Gbps (-STD) / 8.5 Gbps (-1)		225		266	MHz
	40-bit, max data rate = 9.0 Gbps (-STD) / 10.6 Gbps (-1) ¹		225		266	MHz
	64-bit, max data rate = 10.3125 Gbps (-STD) / 12.7 Gbps (-1) ¹		165		200	MHz
	80-bit, max data rate = 10.3125 Gbps (-STD) / 12.7 Gbps (-1) ¹		130		160	MHz

1. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05 V mode. See supply tolerance in the section [Recommended Operating Conditions](#) (see page 6).

Note: Until specified, all modes are non-deterministic. For more information, see [UG0677: PolarFire FPGA Transceiver User Guide](#).

Table 60 • 10GbE (RXAUI)

	Data Rate	Min	Max	Unit
Total transmit jitter	6.25 Gbps			UI
Receiver jitter tolerance	6.25 Gbps			UI

7.5.4 1GbE (1000BASE-T)

The following table describes 1GbE (1000BASE-T).

Table 61 • 1GbE (1000BASE-T)

	Data Rate	Min	Max	Unit
Total transmit jitter	1.25 Gbps			UI
Receiver jitter tolerance	1.25 Gbps			UI

The following table describes 1GbE (1000BASE-X).

Table 62 • 1GbE (1000BASE-X)

	Data Rate	Min	Max	Unit
Total transmit jitter	1.25 Gbps			UI
Receiver jitter tolerance	1.25 Gbps			UI

7.5.5 SGMII and QSGMII

The following table describes SGMII.

Table 63 • SGMII

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter	1.25 Gbps		0.24	UI
Receiver jitter tolerance	1.25 Gbps	0.749		UI

The following table describes QSGMII.

Table 64 • QSGMII

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter	5.0 Gbps		0.3	UI
Receiver jitter tolerance	5.0 Gbps	0.65		UI

7.5.6 SDI

The following table describes SDI.

Table 65 • SDI

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter				UI
Receiver jitter tolerance				UI

7.5.7 CPRI

The following table describes CPRI.

Table 66 • CPRI

	Data Rate	Min	Max	Unit
Total transmit jitter	0.6144 Gbps			UI
	1.2288 Gbps			UI
	2.4576 Gbps			UI
	3.0720 Gbps			UI
	4.9152 Gbps			UI
	6.1440 Gbps			UI
	9.8304 Gbps			UI
	10.1376 Gbps			UI
	12.16512 Gbps ¹			UI
Receive jitter tolerance	0.6144 Gbps			UI
	1.2288 Gbps			UI
	2.4576 Gbps			UI
	3.0720 Gbps			UI
	4.9152 Gbps			UI
	6.1440 Gbps			UI
	9.8304 Gbps			UI
	10.1376 Gbps			UI
	12.16512 Gbps ¹			UI

1. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05 V mode. See supply tolerance in the section [Recommended Operating Conditions \(see page 6\)](#).

7.5.8 JESD204B

The following table describes JESD204B.

Table 67 • JESD204B

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter	3.125 Gbps		0.35	UI
	6.25 Gbps		0.3	UI
	12.5 Gbps ¹			UI
Receive jitter tolerance	3.125 Gbps	0.56		UI
	6.25 Gbps	0.6		UI
	12.5 Gbps ¹			UI

1. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05V mode. See supply tolerance in the section [Recommended Operating Conditions \(see page 6\)](#).

7.6 Non-Volatile Characteristics

The following section describes non-volatile characteristics.

Table 75 • FPGA Programming Cycles Lifetime Factor

Programming T _J	Programming Cycles	LF
–40 °C to 100 °C	500	1
–40 °C to 85 °C	1000	0.8
–40 °C to 55 °C	2000	0.6

Notes:

- The maximum number of device digest cycles is 100K.
- Digests are operational only over the –40 °C to 100 °C temperature range.
- After a program cycle, an additional N digests cycles are allowed with the resultant retention characteristics for the total operating and storage temperature shown.
- Retention is specified for total device storage and operating temperature.
- All temperatures are junction temperatures (T_J).
- Example 1—500 digests cycles are performed between programming cycles. N = 500. The operating conditions are –40 °C to 85 °C T_J. 501 programming cycles have occurred. The retention under these operating conditions is $20 \times LF = 20 \times .8 = 16$ years.
- Example 2—one programming cycle has occurred, N = 1500 digest cycles have occurred. Temperature range is –40 °C to 100 °C. The resultant retention is $10 \times LF$ or 10 years over the industrial temperature range.

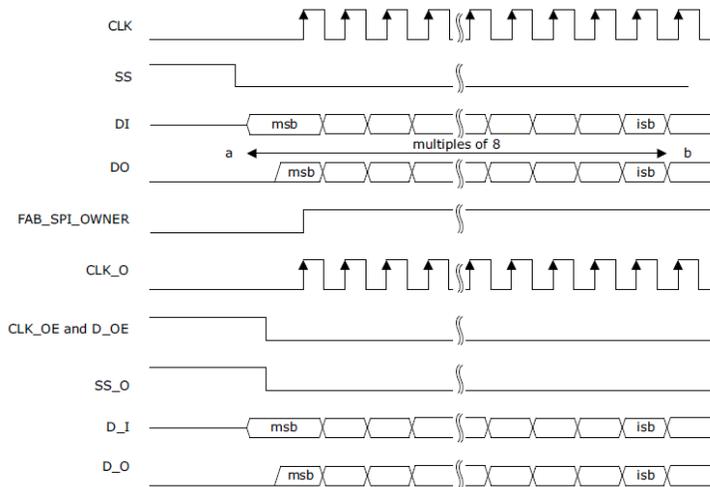
7.6.5 Digest Time

The following table describes digest time.

Table 76 • Digest Times

Parameter	Devices	Typ	Max	Unit
Setup time	All	2		μs
Fabric digest run time	MPF100T, TL, TS, TLS			ms
	MPF200T, TL, TS, TLS	1005	1072	ms
	MPF300T, TL, TS, TLS	1503.9	1582	ms
	MPF500T, TL, TS, TLS			ms
UFS CC digest run time	MPF100T, TL, TS, TLS			μs
	MPF200T, TL, TS, TLS	33.2	35	μs
	MPF300T, TL, TS, TLS	33.2	35	μs
	MPF500T, TL, TS, TLS			μs
sNVM digest run time ¹	MPF100T, TL, TS, TLS			ms
	MPF200T, TL, TS, TLS	4.4	4.8	ms
	MPF300T, TL, TS, TLS	4.4	4.8	ms
	MPF500T, TL, TS, TLS			ms
UFS UL digest run time	MPF100T, TL, TS, TLS			μs
	MPF200T, TL, TS, TLS	46.6	48.8	μs
	MPF300T, TL, TS, TLS	46.6	48.8	μs
	MPF500T, TL, TS, TLS			μs
User key digest run time ²	MPF100T, TL, TS, TLS			μs
	MPF200T, TL, TS, TLS	525.4	543.3	μs
	MPF300T, TL, TS, TLS	525.4	543.3	μs
	MPF500T, TL, TS, TLS			μs

Figure 4 • USPI Switching Characteristics



7.8.4 Tamper Detectors

The following section describes tamper detectors.

Table 91 • ADC Conversion Rate

Parameter	Description	Min	Typ ¹	Max
T _{CONV1}	Time from enable changing from zero to non-zero value to first conversion completes. Minimum value applies when POWEROFF = 0.	420 μs		470 μs
T _{CONVN}	Time between subsequent channel conversions.		480 μs	
T _{SETUP}	Data channel and output to valid asserted. Data is held until next conversion completes, that is >480 μs.	0 ns		
T _{VALID} ²	Width of the valid pulse.	1.625 μs		2 μs
T _{RATE}	Time from start of first set of conversions to the start of the next set. Can be considered as the conversion rate. Is set by the conversion rate parameter.	480 μs	Rate × 32 μs	8128 μs

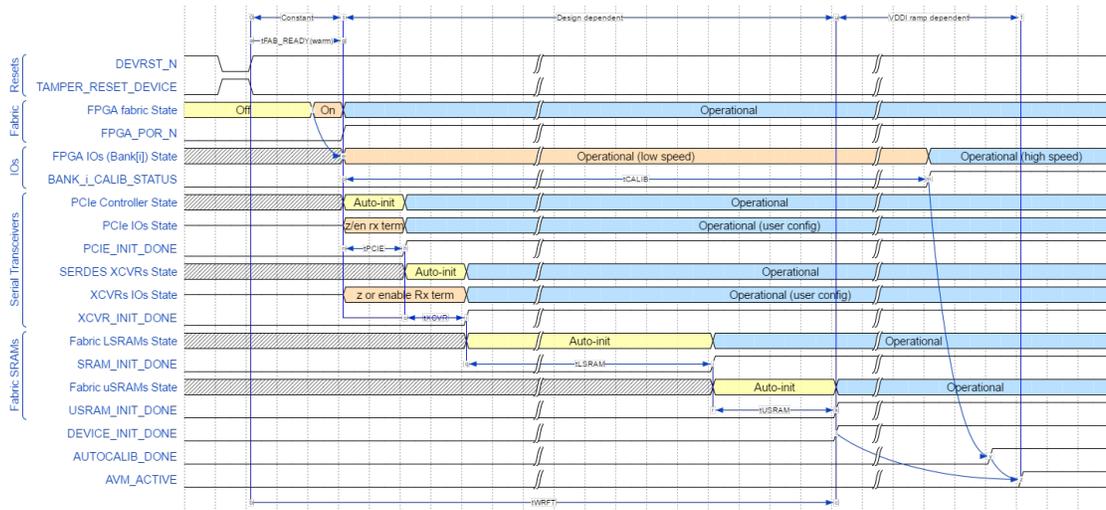
1. Min, typ, and max refer to variation due to functional configuration and the raw TVS value. The actual internal correction time will vary based on the raw TVS value.
2. The pulse width varies depending on the time taken to complete the internal calibration multiplication, this can be up to 375 ns.

Note: Once the TVS block is active, the enable signal is sampled 25 ns before the falling edge of valid. The next enabled channel in the sequence 0-1-2-3 is started; that is, if channel 0 has just completed and only channels 0 and 3 are enabled, the next channel will be 3. When all the enabled channels in the sequence 0-1-2-3 are completed, the TVS waits for the conversion rate timer to expire. The enable signal may be changed at any time if it changes to 4'b0000 while valid is asserted (and 25 ns before valid is de-asserted), then no further conversions will be started.

Table 92 • Temperature and Voltage Sensor Electrical Characteristics

Parameter	Min	Typ	Max	Unit	Condition
Temperature sensing range	-40		125	°C	
Temperature sensing accuracy	-10		10	°C	

Figure 6 • Warm Reset Timing



7.9.3 Power-On Reset Voltages

7.9.3.1 Main Supplies

The start of power-up to functional time (T_{PUFT}) is defined as the point at which the latest of the main supplies (VDD, VDD18, VDD25) reach the reference voltage levels specified in the following table. This starts the process of releasing the reset of the device and powering on the FPGA fabric and I/Os.

Table 97 • POR Ref Voltages

Supply	Power-On Reset Start Point (V)	Note
VDD	0.95	Applies to both 1.0 V and 1.05 V operation.
VDD18	1.71	
VDD25	2.25	

7.9.3.2 I/O-Related Supplies

For the I/Os to become functional (for low speed, sub 400 MHz operation), the (per-bank) I/O supplies (VDDI, VDDAUX) must reach the trip point voltage levels specified in the following table and the main supplies above must also be powered on.

Table 98 • I/O-Related Supplies

Supply	I/O Power-Up Start Point (V)
VDDI	0.85
VDDAUX	1.6

There are no sequencing requirements for the power supplies. However, VDDI3 and must be valid at same time as the main supplies. The other IO supplies (VDDI, VDDAUX) have no effect on power-up of FPGA fabric (that is, the fabric still powers up even if the IO supplies of some IO banks remain powered off).

7.9.4 Design Dependence of T_{PUFT} and T_{WRFT}

Some phases of the device initialization are user design-dependent, as the device automatically initializes certain resources to user-specified configurations if those resources are used in the design. It is necessary to compute the overall power-up to functional time by referencing the following tables and adding the relevant phases, according to the design configuration. The following equation refers to timing parameters specified in the above timing diagrams. Please note T_{PCIE}, T_{XCVR}, T_{LSRAM}, and T_{USRAM} can be found in the PolarFire FPGA device power-up and resets user guide UG0725.

$$T_{PUFT} = T_{FAB_READY(cold)} + \max((T_{PCIE} + T_{XCVR} + T_{LSRAM} + T_{USRAM}), T_{CALIB})$$

$$T_{WRFT} = T_{FAB_READY(warm)} + \max((T_{PCIE} + T_{XCVR} + T_{LSRAM} + T_{USRAM}), T_{CALIB})$$

Note: T_{PCIE}, T_{XCVR}, T_{LSRAM}, T_{USRAM}, and T_{CALIB} are common to both cold and warm reset scenarios.

Auto-initialization of FPGA (if required) occurs in parallel with I/O calibration. The device may be considered fully functional only when the later of these two activities has finished, which may be either one, depending on the configuration, as may be calculated from the following tables. Note that I/O calibration may extend beyond T_{PUFT} (as I/O calibration process is independent of main device power-on and is instead dependent on I/O bank supply relative power-on time and ramp times). The previous timing diagram for power-on initialization shows the earliest that I/Os could be enabled, if the I/O power supplies are powered on before or at the same time as the main supplies.

7.9.5 Cold Reset to Fabric and I/Os (Low Speed) Functional

The following table specifies the minimum, typical, and maximum times from the power supplies reaching the above trip point levels until the FPGA fabric is operational and the FPGA I/Os are functional for low-speed (sub 400 MHz) operation.

Table 99 • Cold Boot

Power-On (Cold) Reset to Fabric and I/O Operational	Min	Typ	Max	Unit
Time when input pins start working – T _{IN_ACTIVE(cold)}	1.17	4.51	7.84	ms
Time when weak pull-ups are enabled – T _{PU_PD_ACTIVE(cold)}	1.17	4.51	7.84	ms
Time when fabric is operational – T _{FAB_READY(cold)}	1.20	4.54	7.87	ms
Time when output pins start driving – T _{OUT_ACTIVE(cold)}	1.22	4.56	7.89	ms

7.9.6 Warm Reset to Fabric and I/Os (Low Speed) Functional

The following table specifies the minimum, typical, and maximum times from the negation of the warm reset event until the FPGA fabric is operational and the FPGA I/Os are functional for low-speed (sub 400 MHz) operation.

Table 100 • Warm Boot

Warm Reset to Fabric and I/O Operational	Min	Typ	Max	Unit
Time when input pins start working – T _{IN_ACTIVE(warm)}	0.91	1.76	2.62	ms
Time when weak pull-ups/pull-downs are enabled – T _{PU_PD_ACTIVE(warm)}	0.91	1.76	2.62	ms
Time when fabric is operational – T _{FAB_READY(warm)}	0.94	1.79	2.65	ms
Time when output pins start driving – T _{OUT_ACTIVE(warm)}	0.96	1.81	2.67	ms

7.9.7 Miscellaneous Initialization Parameters

In the following table, T_{FAB_READY} refers to either T_{FAB_READY(cold)} or T_{FAB_READY(warm)} as specified in the previous tables, depending on whether the initialization is occurring as a result of a cold or warm reset, respectively.

1. With DPA counter measures.

Table 115 • HMAC

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
HMAC-SHA-256 ¹ , 256-bit key	512	7477	2361
	64K	88367	2099
HMAC-SHA-384 ¹ , 384-bit key	1024	13049	2257
	64K	106103	2153

1. With DPA counter measures.

Table 116 • CMAC

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
AES-CMAC-256 ¹ (message is only authenticated)	128	446	9058
	64K	45494	111053

1. With DPA counter measures.

Table 117 • KEY TREE

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
128-bit nonce + 8-bit optype		102457	2751
256-bit nonce + 8-bit optype		103218	2089

Table 118 • SHA

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
SHA-1 ¹	512	2386	1579
	64K	77576	990
SHA-256 ¹	512	2516	884
	64K	84752	938
SHA-384 ¹	1024	4154	884
	64K	100222	938
SHA-512 ¹	1024	4154	881
	64K	100222	935

1. With DPA counter measures.

Table 119 • ECC

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
ECDSA SigGen, P-384/SHA-384 ¹	1024	12528912	6944
	8K	12540448	5643
ECDSA SigGen, P-384/SHA-384	1024	5502928	6155